

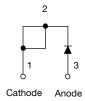
VS-10ETS..FPPbF Series, VS-10ETS..FP-M3 Series

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Vishay Semiconductors

High Voltage, Input Rectifier Diode, 10 A

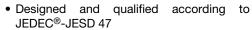




PRODUCT SUMMARY				
TO-220FP				
10 A				
800 V to 1200 V				
1.1 V				
160 A				
150 °C				
Single die				

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction





• UL E78996 approved

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





FREE

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS		
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	12.0	16.0	А		

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES			
I _{F(AV)}	Sinusoidal waveform	10	А		
V _{RRM}	Range	800/1200	V		
I _{FSM}		160	А		
V _F	10 A, T _J = 25 °C	1.1	V		
T _J		-40 to +150	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-10ETS08FPPbF, VS-10ETS08FP-M3	800	900	0.5		
VS-10ETS12FPPbF, VS-10ETS12FP-M3	1200	1300	0.5		



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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	135	Α
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	91	A ² s
	1-1	10 ms sine pulse, no voltage reapplied	130	A-S
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1300	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	T _{.I} = 150 °C		20	$m\Omega$
Threshold voltage	V _{F(TO)}	1 IJ = 150 C		0.82	V
Maximum variance leakage accurrent	1	T _J = 25 °C	V - Potod V	0.05	mA
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	0.50	IIIA

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS
Maximum junction and stor temperature range	age	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistant junction to case	ce,	R_{thJC}	DC operation	2.5	
Maximum thermal resistant junction to ambient	ce,	R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque max	maximum			12 (10)	(lbf ⋅ in)
Marking davisa			Consisted TO 000 FULL DAY	10ETS08FP	
Marking device			Case style TO-220 FULL-PAK	10ETS	S12FP

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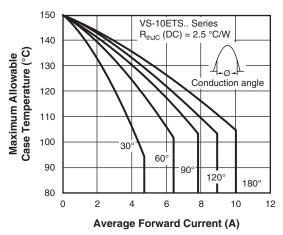


Fig. 1 - Current Rating Characteristics

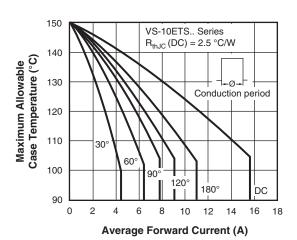


Fig. 2 - Current Rating Characteristics

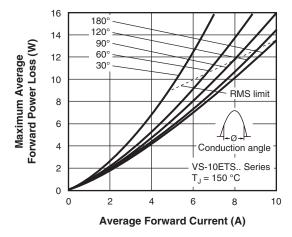


Fig. 3 - Forward Power Loss Characteristics

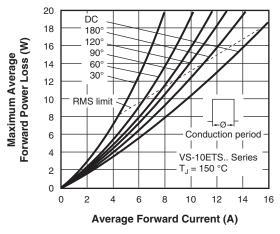


Fig. 4 - Forward Power Loss Characteristics

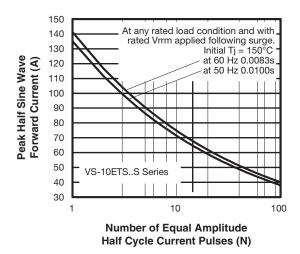


Fig. 5 - Maximum Non-Repetitive Surge Current

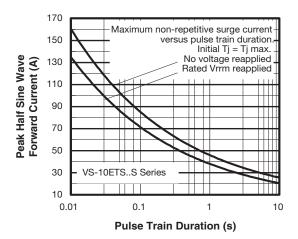


Fig. 6 - Maximum Non-Repetitive Surge Current

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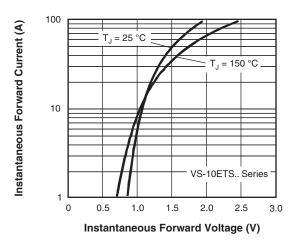


Fig. 7 - Forward Voltage Drop Characteristics

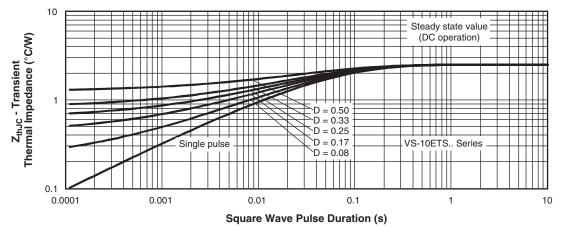


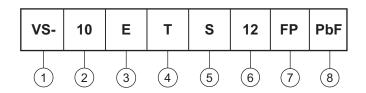
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

3 - Circuit configuration:

E = single diode

- Package:

T = TO-220

5 - Type of silicon:

S = standard recovery rectifier

08 = 800 V

7 - FULL-PAK

8 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

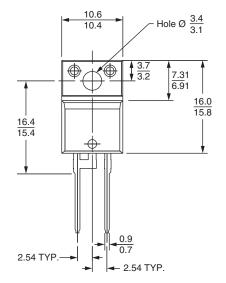
12 = 1200 V

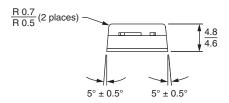
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETS08FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETS08FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETS12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETS12FP-M3	50	1000	Antistatic plastic tubes			

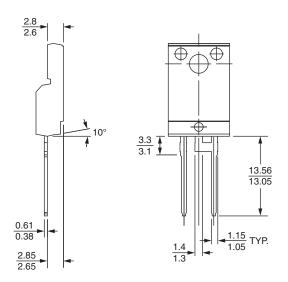
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95005			
Part marking information	TO-220FP PbF	www.vishay.com/doc?95009			
	TO-220FP -M3	www.vishay.com/doc?95440			

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DIMENSIONS in millimeters







Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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